



Features

- RoHS compliant*
- Glass passivated chip
- Low reverse leakage current
- Low forward voltage drop
- High current capability

CD214B-R250~R21000 Glass Passivated Rectifiers

General Information

The markets of portable communications, computing and video equipment are challenging the semiconductor industry to develop increasingly smaller electronic components. Bourns offers Glass Passivated Rectifiers for rectification applications, in compact chip DO-214AA (SMB) size format, which offer PCB real estate savings and are considerably smaller than most competitive parts. The Glass Passivated Rectifier Diodes offer a forward current of 2.0 A with a choice of repetitive peak reverse voltage of 50 V up to 1000 V.

Bourns® Chip Diodes conform to JEDEC standards, are easy to handle on standard pick and place equipment and their flat configuration minimizes roll away.

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

Parameter	Symbol	CD214B-							Unit
		R250	R2100	R2200	R2400	R2600	R2800	R21000	
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Max. Average Forward Rectified Current ¹	$I_{(AV)}$	2.0							A
DC Reverse Current @ Rated DC Blocking Voltage (@ $T_J = 25^\circ\text{C}$)	I_R	5.0							μA
DC Reverse Current @ Rated DC Blocking Voltage (@ $T_J = 125^\circ\text{C}$)	I_R	30							μA
Typical Junction Capacitance ²	C_J	25							pF
Maximum Instantaneous Forward Voltage @ 1 A	V_F	1.0							V
Typical Thermal Resistance ³	$R_{\theta JL}$	16							$^\circ\text{C/W}$
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	65							A

Notes:

1 See Forward Derating Curve.

2 Measured @ 1.0 MHz and applied reverse voltage of 4.0 VDC.

3 Thermal resistance from junction to ambient and from junction to lead P.C.B. mounted on 0.2" x 0.2" (5.0 mm x 5.0 mm) copper pad areas.

Thermal Characteristics (@ $T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

Parameter	Symbol	CD214B-R250~R21000	Unit
Operating Temperature Range	T_J	-65 to +175	$^\circ\text{C}$
Storage Temperature Range	T_{STG}	-65 to +170	$^\circ\text{C}$

*RoHS Directive 2002/95/EC Jan 27, 2003 including Annex.

Specifications are subject to change without notice.

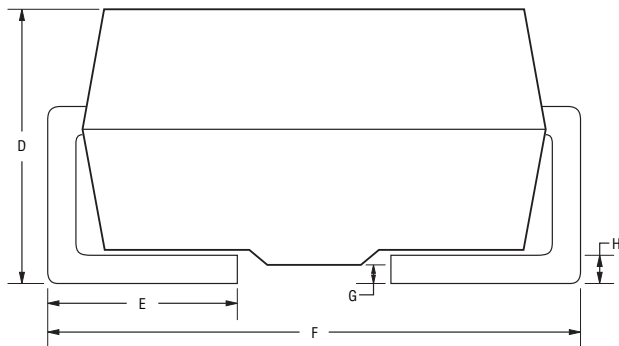
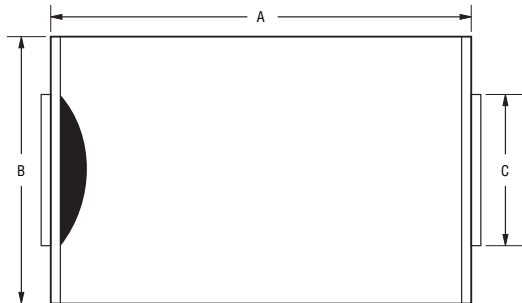
Customers should verify actual device performance in their specific applications.

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Product Dimensions

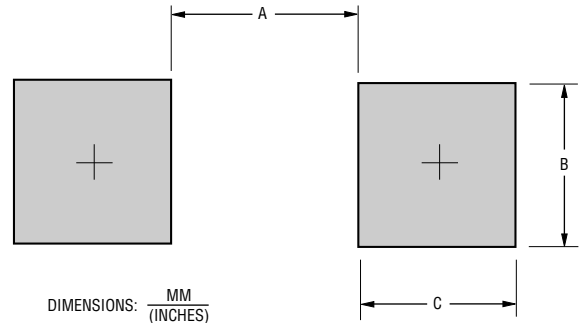
This is an RoHS compliant product. It is a molded plastic package. A cathode band indicates the polarity. The package weighs approximately 0.064 g. The package and dimensions are shown below.



Dimensions	
A	$\frac{4.06 - 4.57}{(0.167 - 0.187)}$
B	$\frac{3.30 - 3.94}{(0.130 - 0.150)}$
C	$\frac{1.96 - 2.21}{(0.075 - 0.087)}$
D	$\frac{2.01 - 2.62}{(0.079 - 0.096)}$
E	$\frac{0.76 - 1.52}{(0.039 - 0.055)}$
F	$\frac{5.21 - 5.59}{(0.197 - 0.236)}$
G	$\frac{0.05 - 0.20}{(0.00196 - 0.00787)}$
H	$\frac{0.15 - 0.31}{(0.006 - 0.016)}$

DIMENSIONS: $\frac{\text{MM}}{(\text{INCHES})}$

Recommended Pad Layout



Dimension	SMB (DO-214AA)
A (Max.)	$\frac{2.69}{(0.106)}$
B (Min.)	$\frac{2.10}{(0.083)}$
C (Min.)	$\frac{1.27}{(0.050)}$

How To Order

CD 214B - R 2 50

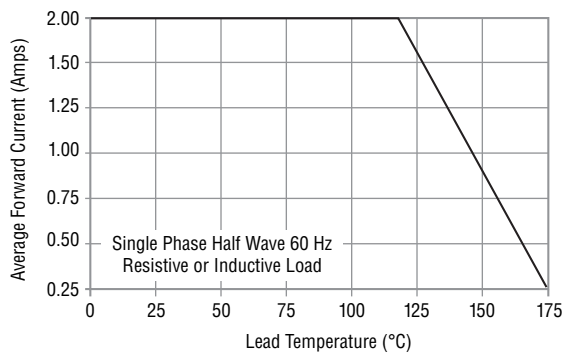
Common Code _____
 Chip Diode _____
 Package _____
 • 214B = SMB/DO-214AA
 Model _____
 R = Glass Pasivated Rectifiers
 Forward Current I_{AV} _____
 2 = 2 A
 Reverse Voltage _____
 50 = 50 V
 100 = 100 V
 200 = 200 V
 400 = 400 V
 600 = 600 V
 800 = 800 V
 1000 = 1000 V

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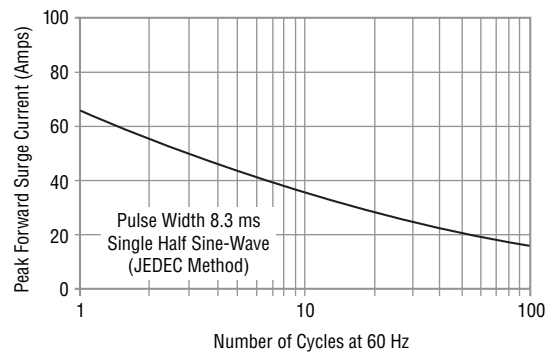
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Rating and Characteristic Curves

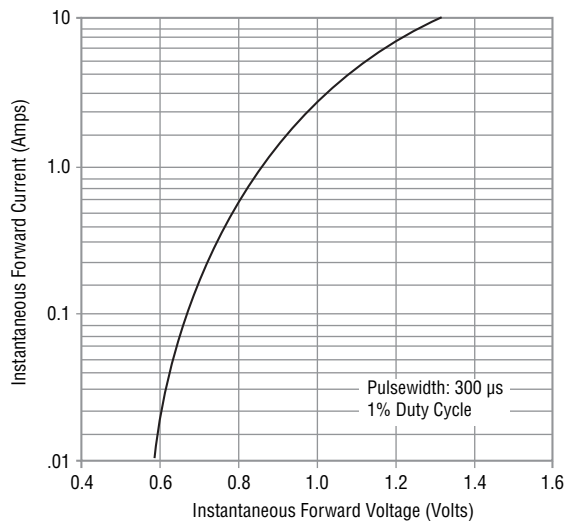
Forward Current Derating Curve



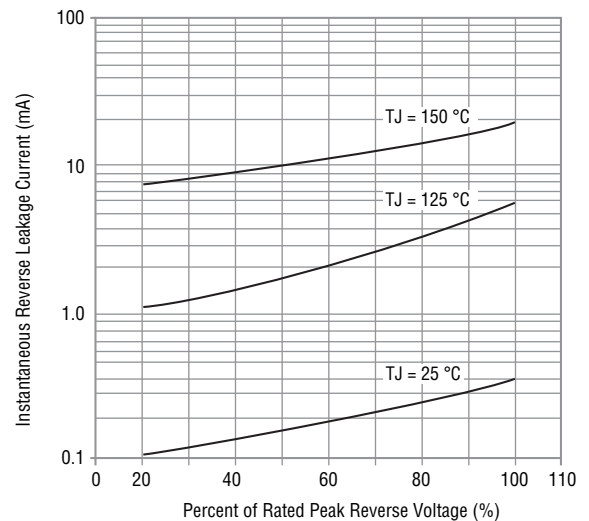
Non-Repetitive Surge Current



Forward Characteristics

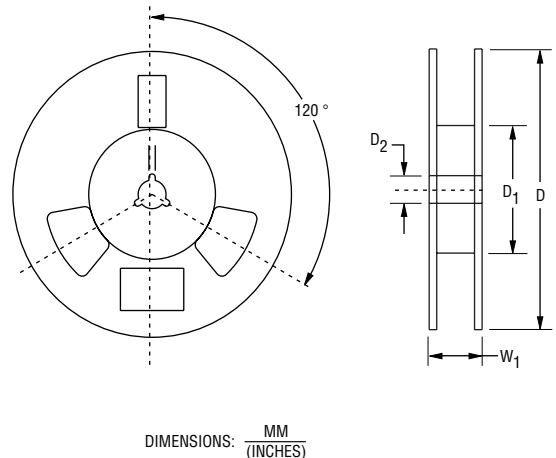


Reverse Characteristics



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The surface mount product is packaged in an 8 mm x 4 mm tape and reel format per EIA-481 standard.



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Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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